Characteristics T1010H

1 Characteristics

Table 2. Absolute maximum ratings

Symbol	Parameter			Value	Unit
I _{T(RMS)}	On-state rms current (full sine wave)	D ² PAK, TO-220AB	T _c = 135 °C	10	Α
1 .	Non repetitive surge peak on-state	F = 60 Hz	t = 16.7 ms	105	А
I _{TSM}	current (full cycle, T _j initial = 25 °C)	F = 50 Hz	t = 20 ms	100	
l ² t	I ² t Value for fusing	t _p = 10 ms		66	A ² s
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$	F = 120 Hz		50	A/μs
V _{DSM} /V _{RSM}	Non repetitive surge peak off-state voltage $t_p = 10 \text{ ms} \qquad \qquad T_j = 25 \text{ °C}$		T _j = 25 °C	V _{DRM} /V _{RRM} + 100	V
I _{GM}	Peak gate current $t_p = 20 \ \mu s$ $T_j = 150 \ ^{\circ}C$		4	Α	
P _{G(AV)}	Average gate power dissipation $T_j = 150 ^{\circ}\text{C}$			1	W
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 150	°C

Table 3. Electrical characteristics ($T_j = 25$ °C, unless otherwise specified)

Symbol	Test conditions	Quadrant	Min.	Max.	Unit
I _{GT}	$V_D = 12 \text{ V} R_L = 33 \Omega$	1 - 11 - 111	1	10	mA
V _{GT}	AD = 15 A UF = 22.75	1 - 11 - 111		1.0	V
V_{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$	1 - 11 - 111	0.15		\
I _H ⁽¹⁾	I _T = 100 mA			25	mA
	1 - 1 2 1	I - III		30	— mA
ال	$I_{G} = 1.2 I_{GT}$	II		35	
dV/dt (1)	V _D = 67% V _{DRM,} gate open, T _j = 150 °C		75		V/µs
(dl/dt)c (1)	Logic level, 0.1 V/μs, T _j = 150 °C		14.4		A/ms
(di/dt)C · /	Logic level, 15 V/µs, T _j = 150 °C		3.8		

^{1.} For both polarities of A2 referenced to A1.

T1010H Characteristics

Table 4. Static characteristics

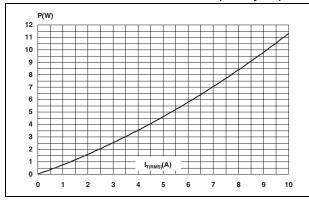
Symbol	Test cond	Value	Unit		
V _T ⁽¹⁾	I _{TM} = 14.1 A, t _p = 380 μs	T _j = 25 °C	MAX.	1.5	V
V _{t0} (1)	Threshold voltage	T _j = 150 °C	MAX.	0.80	V
R _d ⁽¹⁾	Dynamic resistance	T _j = 150 °C	MAX.	41.0	mΩ
I _{DRM} I _{RRM}	V - V	T _j = 25 °C	MAX.	5	μΑ
	$V_{DRM} = V_{RRM}$	T _j = 150 °C	MAX.	3.6	
	V _D /V _R = 400 V (at peak mains voltage)	T _j = 150 °C	MAX.	3.0	mA
	V _D /V _R = 200 V (at peak mains voltage)	T _j = 150 °C	MAX.	2.5	

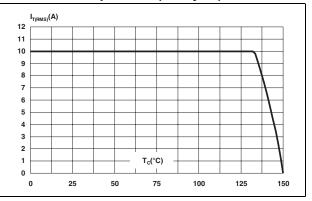
^{1.} for both polarities of A2 referenced to A1.

Table 5. Thermal resistance

Symbol	Parameter			Value	Unit
R _{th(j-c)}	Junction to case (AC)		D ² PAK / TO-220AB	1.50	
D	Junction to ambient	$S = 1 \text{ cm}^2$	D ² PAK	45	°C/W
R _{th(j-a)}	Junction to ambient		TO-220AB	60	

Figure 1. Maximum power dissipation versus Figure 2. On-state rms current versus case on-state rms current (full cycle) temperature (full cycle)

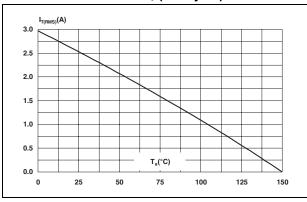




Characteristics T1010H

Figure 3. On-state rms current versus ambient temperature (free air convection, (full cycle)

Figure 4. Relative variation of thermal impedance, versus pulse duration

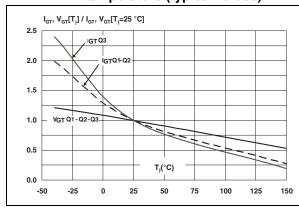


1.E-02

1.E-03

Figure 5. Relative variation of gate trigger current and voltage versus junction temperature (typical values)

Figure 6. Relative variation of holding and latching current versus junction temperature (typical values)



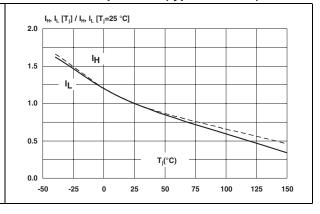
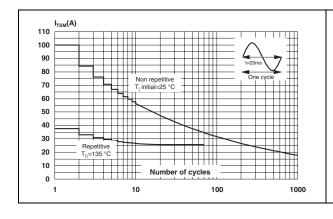
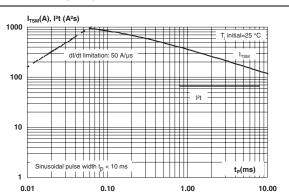


Figure 7. Surge peak on-state current versus Figure 8. number of cycles

Non-repetitive surge peak on-state current and corresponding value of I²t



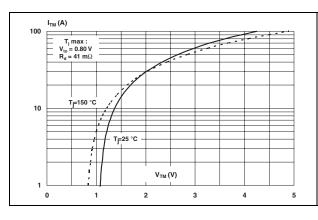


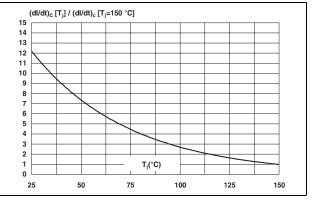
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Figure 9. On-state characteristics (maximum Figure 10. values)

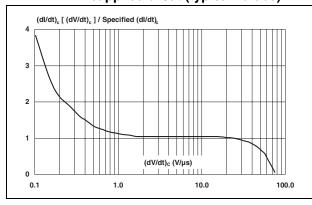
Relative variation of critical rate of decrease of main current versus junction temperature





Relative variation of critical rate of Figure 12. Figure 11. decrease of main current versus reapplied dV/dt (typical values)

Relative variation of static dV/dt immunity versus junction temperature



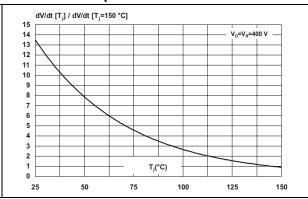
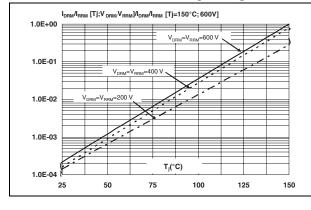
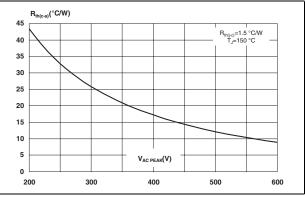


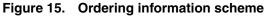
Figure 13. Variation of leakage current versus Figure 14. Acceptable case to ambient thermal junction temperature for different values of blocking voltage

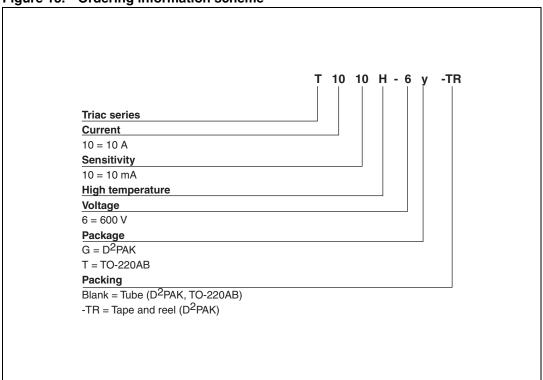
resistance versus repetitive peak off-state voltage





2 Ordering information scheme





T1010H Package information

3 Package information

- Epoxy meets UL94, V0
- Recommended torque 0.4 to 0.6 N⋅m

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Table 6. D²PAK dimensions

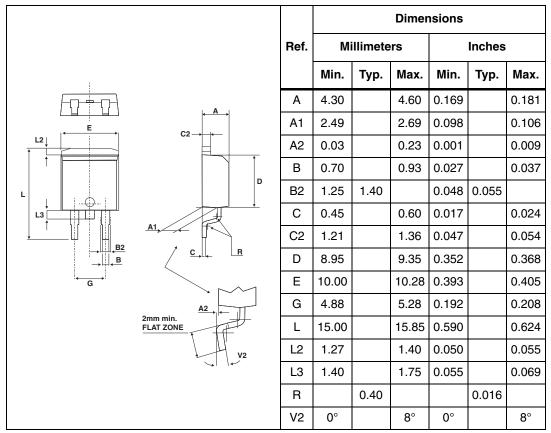
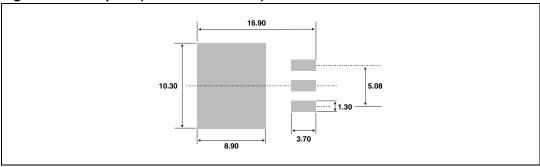
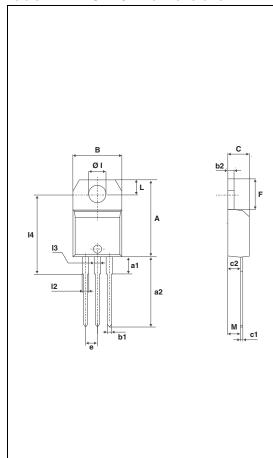


Figure 16. Footprint (dimensions in mm)



Package information T1010H

Table 7. TO-220AB dimensions



	Dimensions					
Ref.	Millimeter		rs Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
В	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
С	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
е	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
14	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
12	1.14	_	1.70	0.044		0.066
13	1.14		1.70	0.044		0.066
М		2.60			0.102	

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4 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
T1010H-6G	T1010H 6G	D ² PAK	1.5 g	50	Tube
T1010H-6G-TR	T1010H 6G	D ² PAK	1.5 g	1000	Tape and reel
T1010H-6T	T1010H 6T	TO-220AB	2.3 g	50	Tube

5 Revision history

Table 9. Document revision history

Date	Revision	Changes
15-May-2009	1	First issue.

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